

# Thin Film Surface Mount Amplifier 1 to 1000 MHz

### **Description**

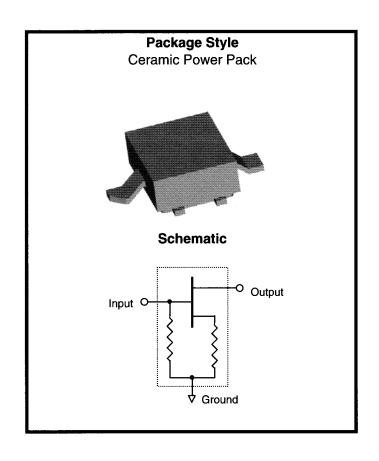
The **ASMA-301** is a 50 Ohm GaAs FET amplifier featuring internal biasing and feedback networks. The **ASMA-301** will find application in RF/Microwave systems up to 2.0 GHz requiring superior broadband, high linearity and excellent stability.

#### **Features**

- Unconditionally Stable 50 Ohm Gain Block
- Cascadable Broadband Performance
- Single Positive Supply Operation
- Usable to 2 GHz with Simple External Matching

Maximum Ratings Tc = 25 °C

SYMBOL	RATING	UNITS	
018000	11211170	ONTO	
$V_{D}$	<b>V</b> <sub>D</sub> 15		
P <sub>IN</sub>	+25	dBm	
T <sub>Ch</sub>	+175	°C	
TSOLDER	+260 °C for 10 Seconds	°C	
T <sub>STG</sub>	-65 to +150	°C	



#### ELECTRICAL SPECIFICATIONS V<sub>D</sub> = 11.0 Vdc

	Characteristics	T <sub>C</sub> = +25 °C	T <sub>C</sub> = 0 to +50 °C		
SYMBOL		TYPICAL	MINIMUM	MAXIMUM	UNITS
BW	Frequency Range		1	1,000	MHz
G₽	Small Signal Power Gain	10.5	10		dB
$\Delta G_{P}$	Gain Flatness	± 0.6		± 1.0	dB
NF	Noise Figure (100 MHz)	5.0		6.5	dB
P <sub>1dB</sub>	Power Output at 1dB Compression	+28	+27		dBm
VOWD	Input	2.3:1		2.5:1	
VSWR	Output	3.0:1		3.5:1	
REV.	Reverse Isolation	22			dB
ISOL.					
$I_{P2}$	Two Tone 2 <sup>nd</sup> Order Intercept Point	+54			dBm
l <sub>P3</sub>	Two Tone 3 <sup>rd</sup> Order Intercept Point	+42			dBm
H <sub>P2</sub>	Single Tone 2 <sup>nd</sup> Harmonic Intercept Point	+60			dBm
I <sub>D</sub>	Device Current	200		240	mA

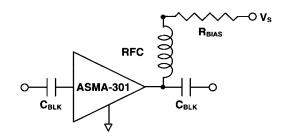


## ASMA203 26dBm, 50 Ohm Amplifier 1-300MHz

Electrical Specifications  $I_D = 250 \text{ mA}$ 

		T <sub>C</sub> = 25°C	T <sub>C</sub> = 0 to 50°C		
SYMBOL	CHARACTERISTICS	TYPICAL	MINIMUM	MAXIMUM	UNITS
BW	Frequency Range		1	300	MHz
$G_{P}$	Small Signal Power Gain	13.0	12.0		dB
$\Delta G_P$	Gain Flatness	± 0.2		± 0.5	dB
NF	Noise Figure (100 MHz)	6.0			dB
P <sub>1dB</sub>	Power Output at 1 dB Compression	+27	+26.0		dBm
	Input/	2.0:1		2.5:1	
VSWR	Output	2.2:1		2.5:1	
REV ISO.	Reverse Isolation	19			dB
I <sub>P2</sub>	Two Tone 2 <sup>nd</sup> Order Intercept Point	+53			dBm
I <sub>P3</sub>	Two Tone 3 <sup>rd</sup> Order Intercept Point	+41			dBm
H <sub>P2</sub>	Single Tone 2 <sup>nd</sup> Harmonic Intercept Point	+59			dBm
$V_{D}$	Device Voltage	12.5	11.5	13.5	V

## **Typical Bias Configuration**



Typical Component Values

Frequency MHz	<b>С</b> <sub>вLК</sub> pF	<b>RFC</b> μΗ	$ m m{R_{BIAS}}$	V <sub>s</sub> V
100	1,500	75	5	12
500	330	15	20	15
1000	180	0.075	65	24

## **Outline Drawing**

